



Institute Separative Chemistry of Marcoule (ICSM)

Behavior of mesoporous thin films (SiO₂, C) under ion irradiation

Adaptive Nanomaterials Laboratory for Energy

**A. AZEDDIOUI, P. de LAHARPE, C. REY, G. TOQUER, C.
GRYGIEL*, X. DESCHANELS**

ICSM, CEA, CNRS, ENSCM, Univ Montpellier, Marcoule, France

*CIMAP, CEA-CNRS-ENSICAEN-UNICAEN Bd. Henri Becquerel, Caen, France

Xavier.deschanel@cea.fr

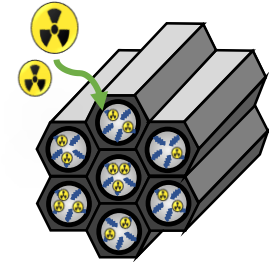


UNIVERSITÉ DE
MONTPELLIER

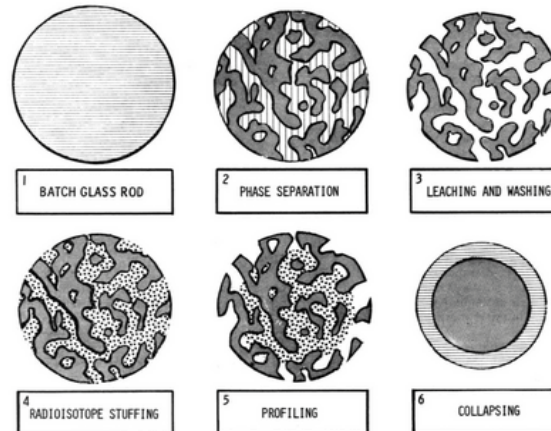


Model materials → Silicas

- ✓ Chemically similar to **glass**
- ✓ **Mesoporous** : $\Phi = 2 - 50 \text{ nm}$
- ✓ **Organized**
- ✓ High surface area (500–1000 m²/g), easily functionalized, selective for radionuclides
→ Applications: nuclide separation and packaging

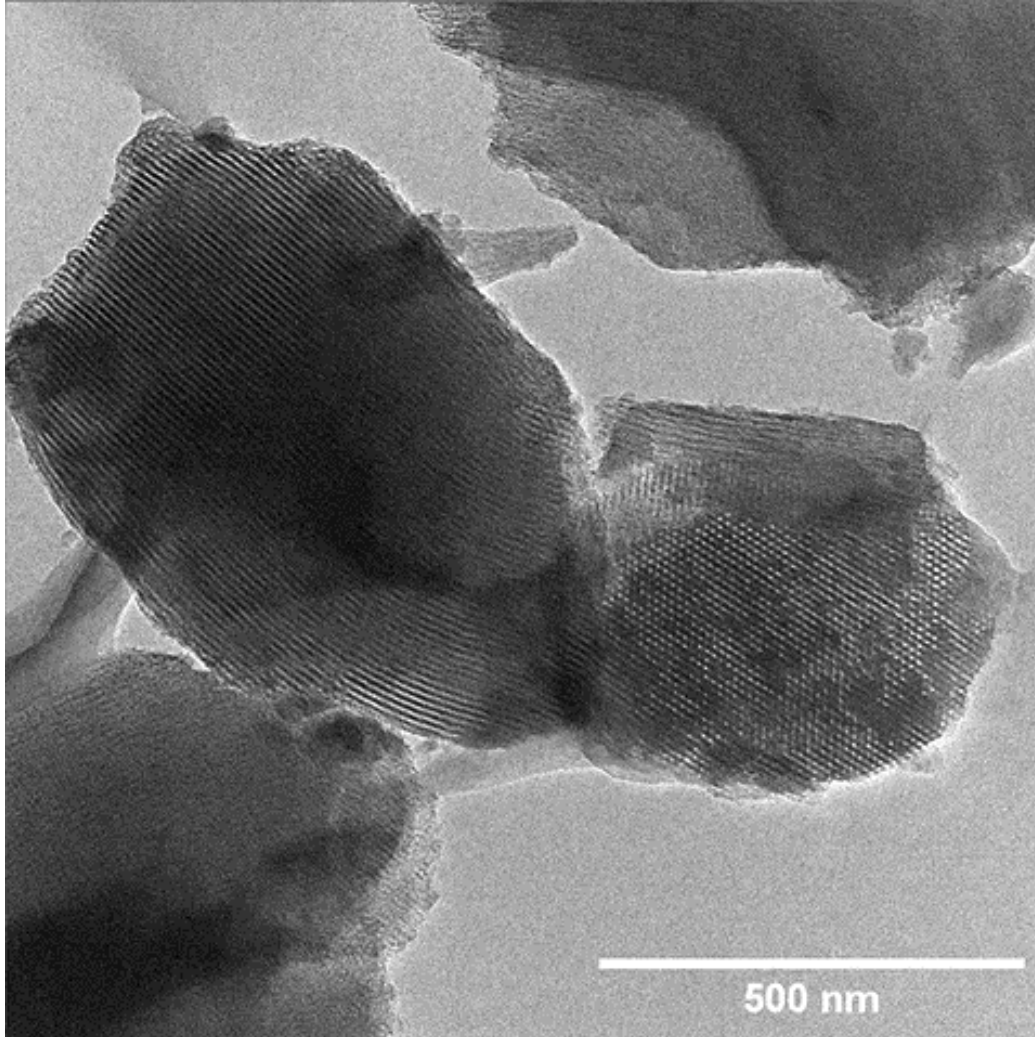


Vycor glasses (Simmons 1979)



Radiation damage in mesoporous silica

- Xe: 600keV – SiO₂ mesoporous SBA-15 at -160°C
 $\phi < 6.25 \times 10^{14}$ ions/cm²
- **Collapse of the mesoporosity**



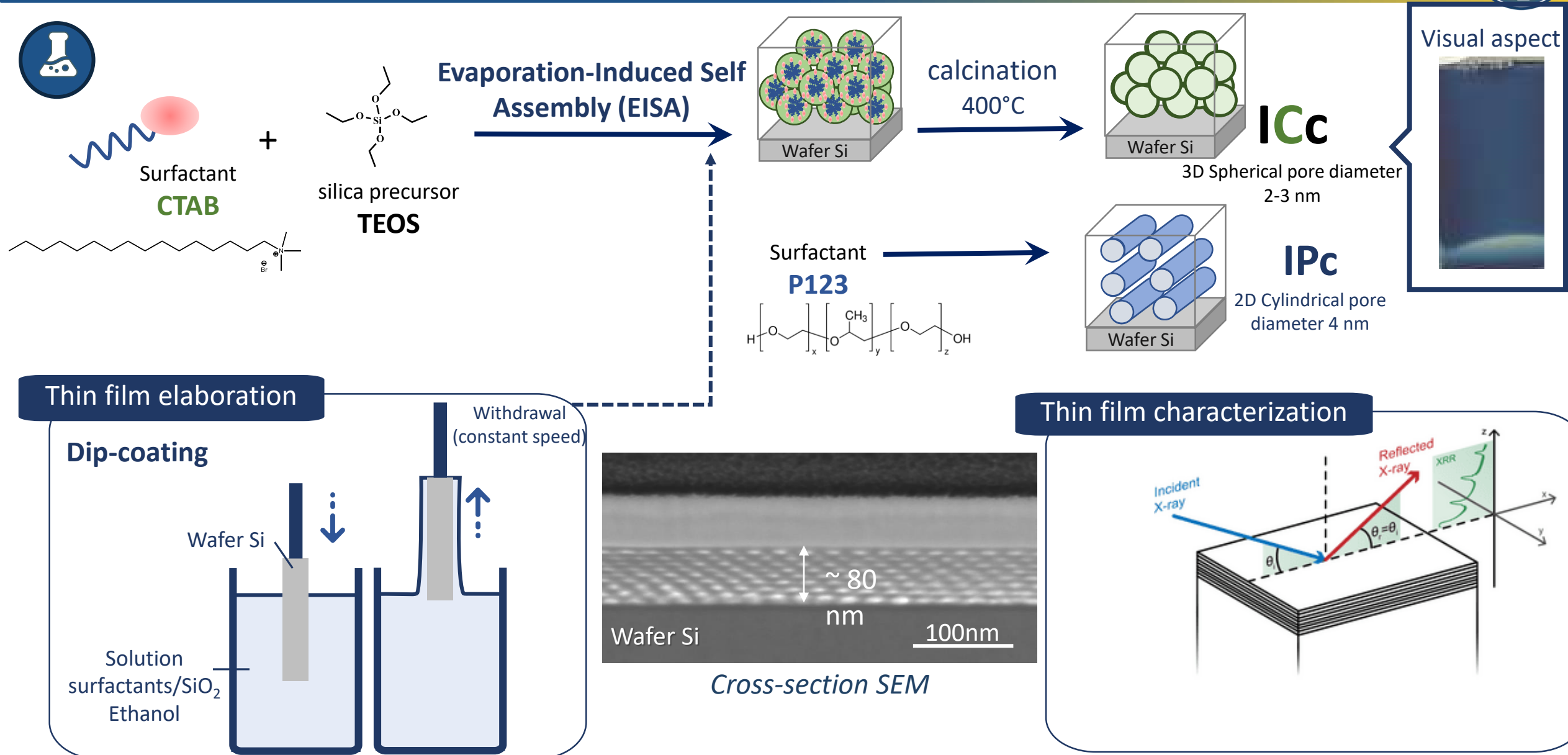
**Radiation damage in
mesoporous silica**



Densification

MIAMI-2 platform Huddersfield University
Collaboration **Anamul. H Mir**

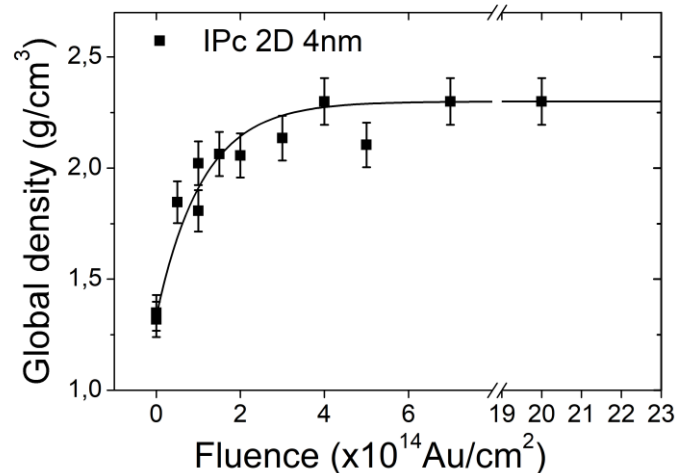
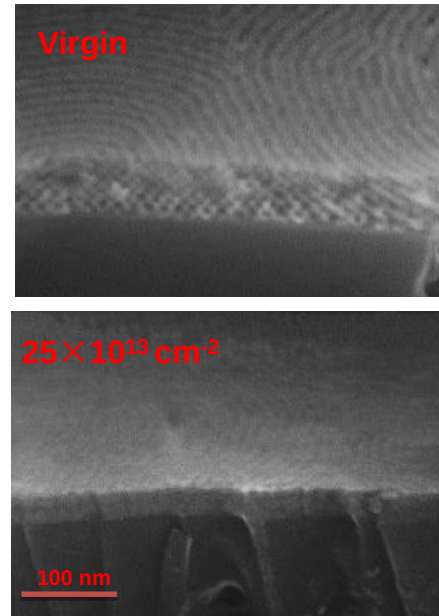
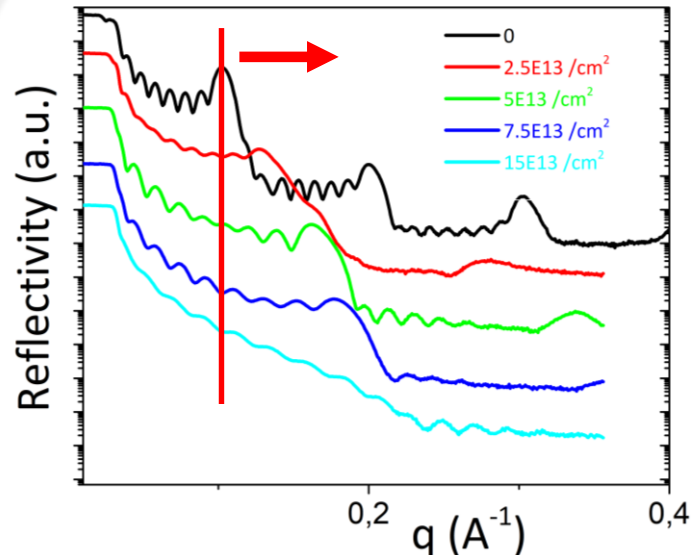
Synthesis: Mesoporous silica thin film (sol-gel process)



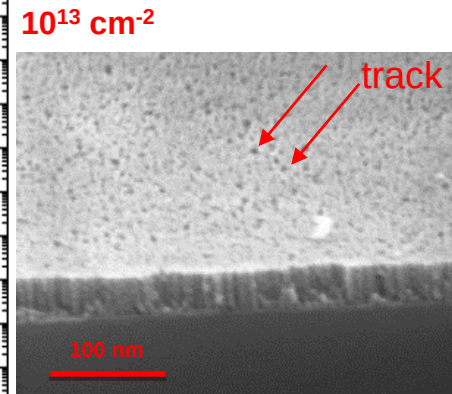
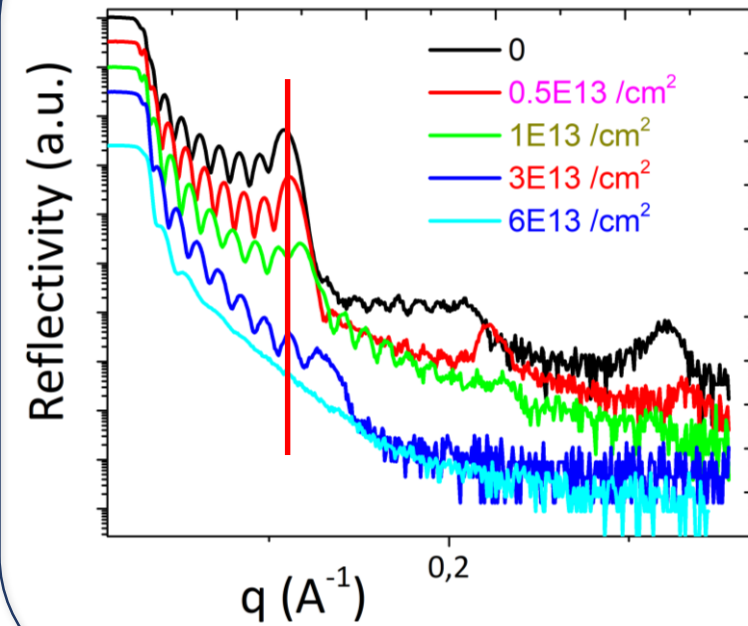
Mesoporous silica (IPc): Collapse versus stopping power



Au 0,5 MeV : $dE/dx=4,2\text{keV/nm}$



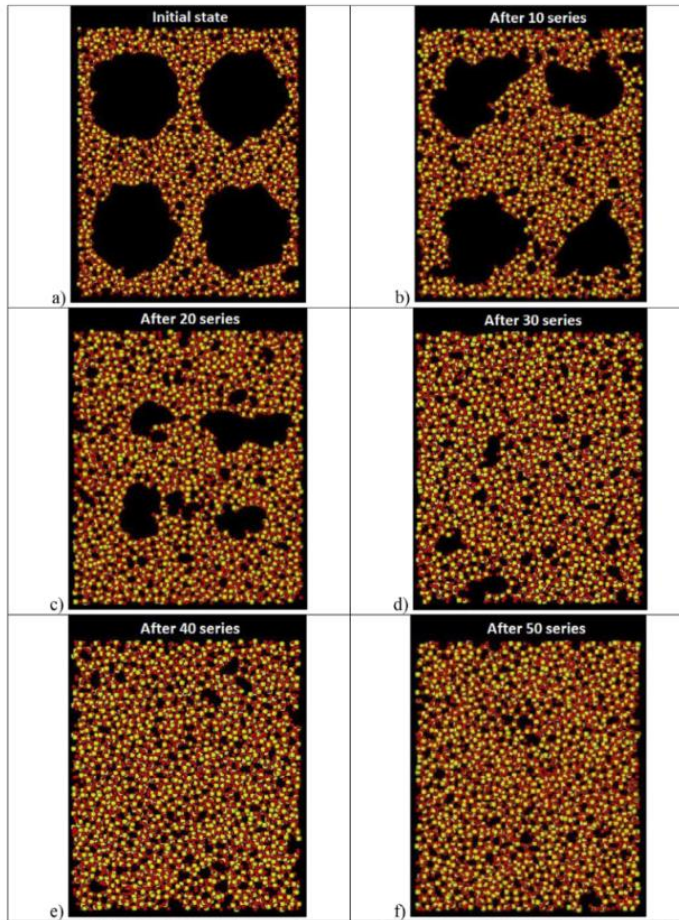
Xe 92MeV : $dE/dx=11\text{keV/nm}$



Mesostructure collapse

- High $dE/dx \rightarrow$ Track formation
- Low $dE/dx \rightarrow$ to be precise

Molecular dynamics of 1.2 keV U impact



Progressive shrinkage of the porous structure with the accumulation of **ballistic effect**

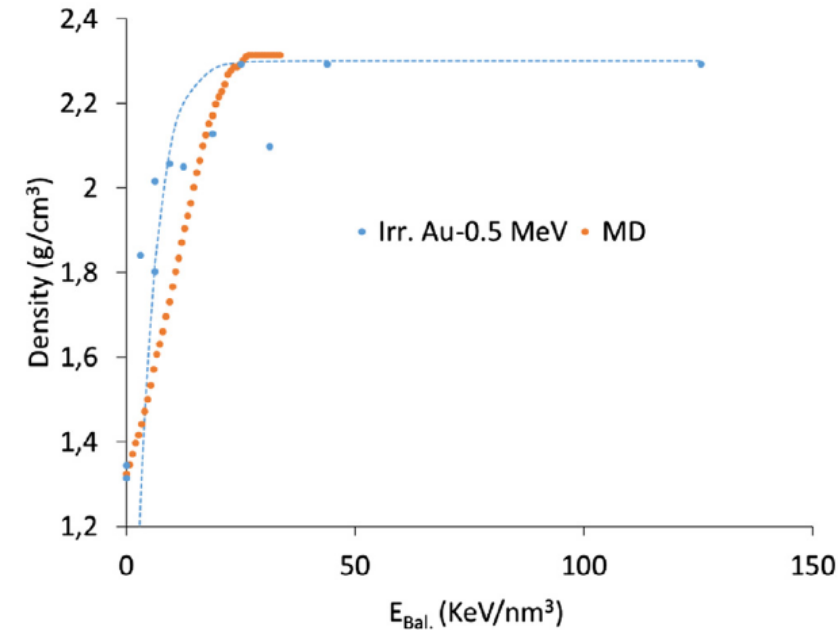


Fig. 12. Comparison between experimental and modelling results. E_{bal} corresponds to the energy deposited by ballistic effects.

Possible **densification** mechanism:

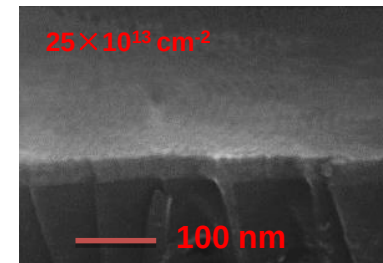
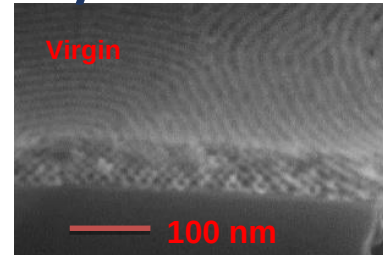
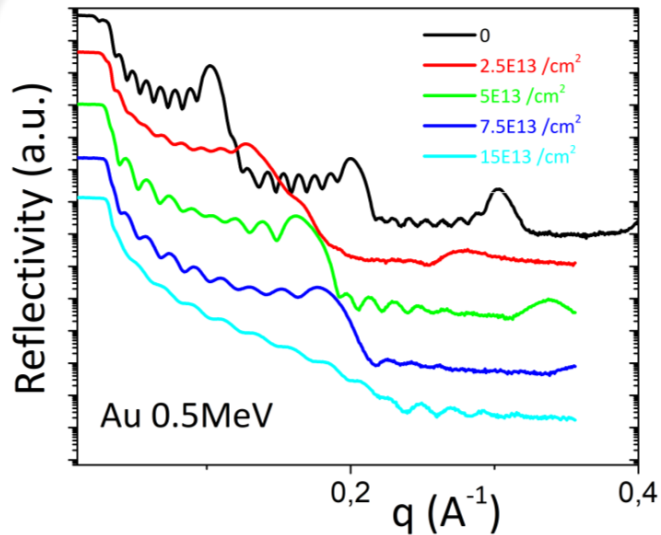


Low temperature sintering process assisted by ballistic diffusion

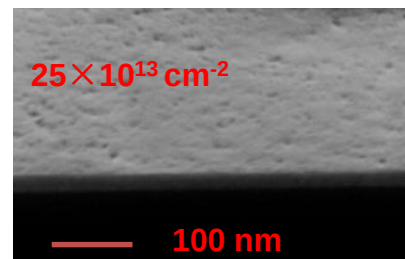
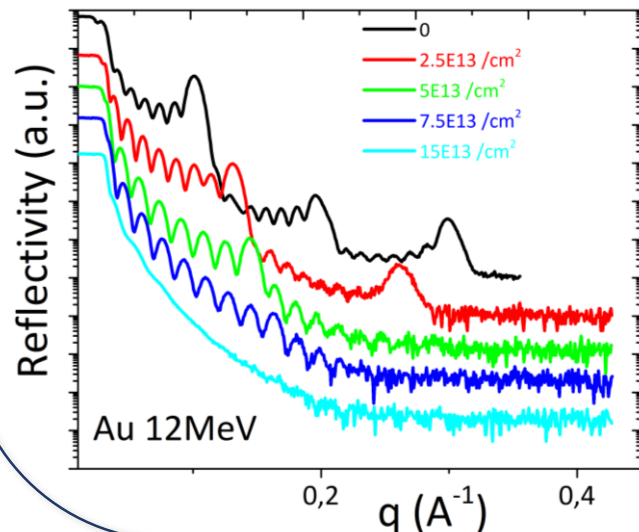
Mesoporous silica (IPc) - Irradiation versus Heating



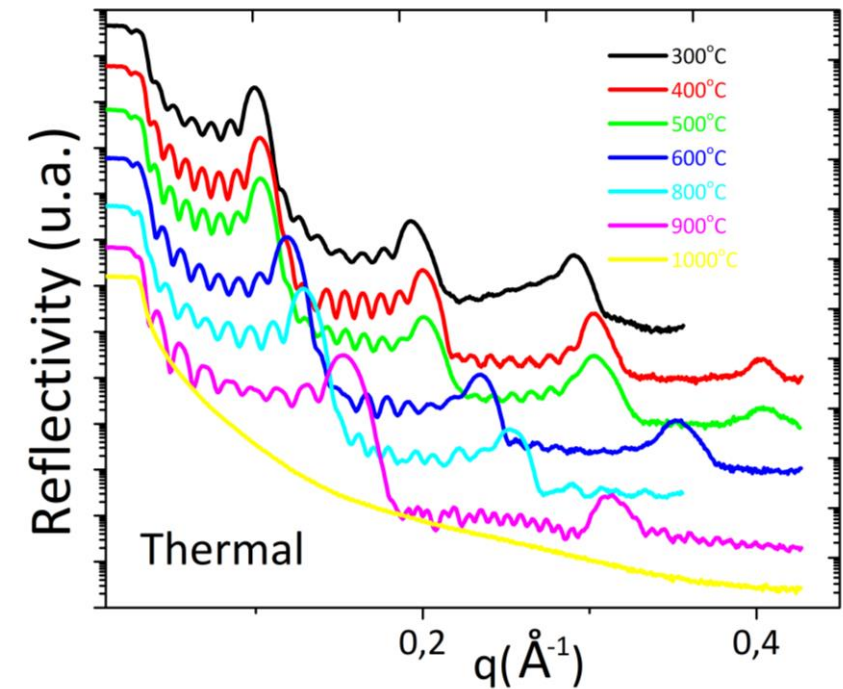
Au 0,5 MeV : $dE/dx=4,2\text{keV/nm}$



Au 12 MeV : $dE/dx=3,8\text{keV/nm}$



Heating : 300 to 1000°C



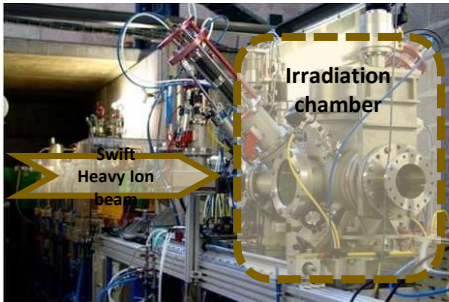
Analogy between heating and irradiation at low-stopping-power
Irradiation-induced sintering process

Observed **densification** mechanism:

→ Irradiation-induced **sintering process** within mesoporous silica



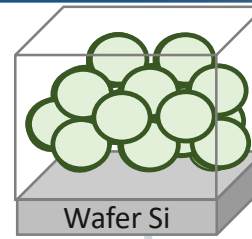
Contribution of irradiation and heating were performed simultaneously (ballistic/electronic processes, stopping power)



GANIL



ICc
and
ICp



Characterization

- Characterization
- **X-ray reflectivity** : density, thickness, roughness
 - **FTIR** : Si-O-Si network
 - **SEM/TEM** : morphology

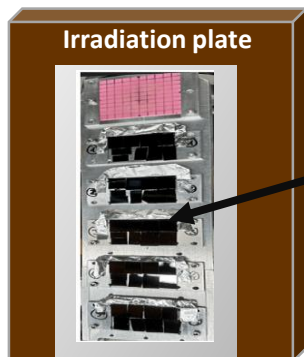
Irradiation :

- **Electronics** (Ar, Ne)
- **Ballistics** (Au)

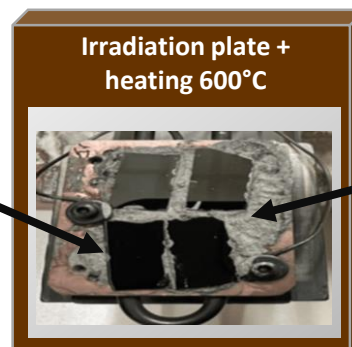
Irradiation

Irradiation + Heating

Heating only



Sample



silver glue

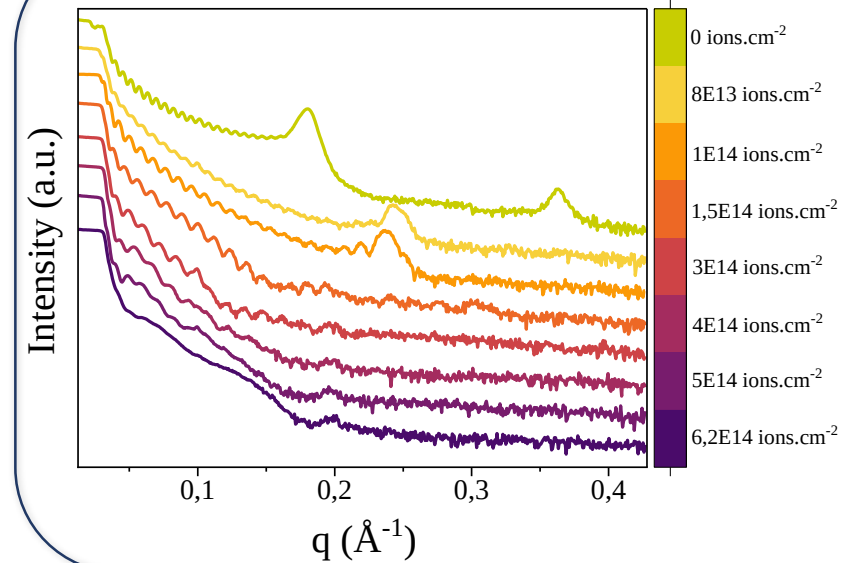
Electronic (Se)

Ion	Energie MeV/A	Se keV/nm	Sn keV/nm	Flux Ions/(cm ² .s)	Beamline
²² Ne	0.98	2.2	2.79E-03	7~8 ^e 9	IRRSUD GANIL, Caen
³⁶ Ar	0.98	4.5	1.00E-02	8~9 ^e 9	IRRSUD GANIL, Caen
¹⁹⁷ Au	0,025	1.0	3.2	6~9 ^e 10	JANNUS, Orsay

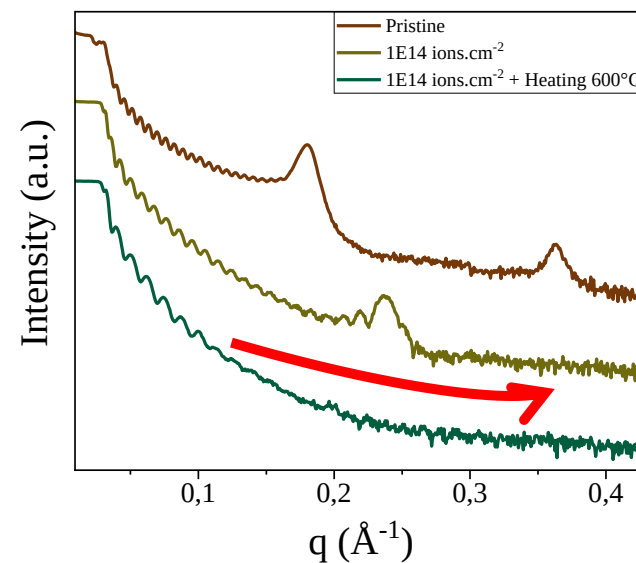
Ballistic (Sn)

Mesoporous silica ICc - combined effect of T + radiation

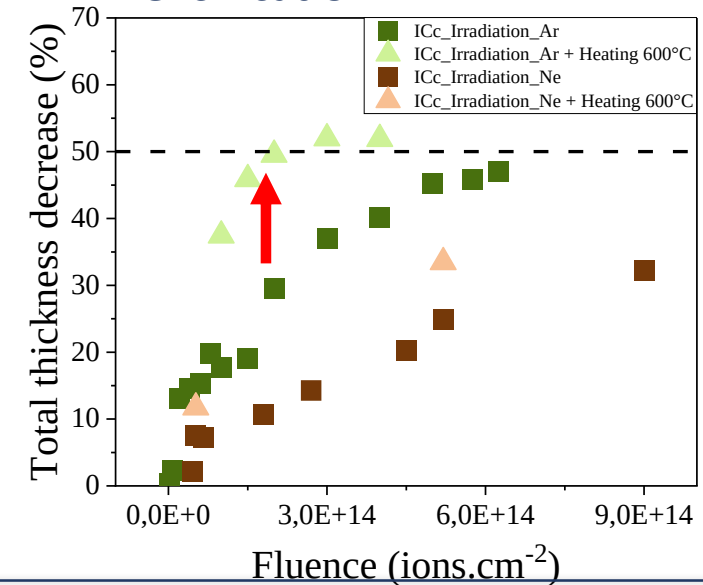
^{36}Ar – $dE/dx = 4,5 \text{ keV/nm}$



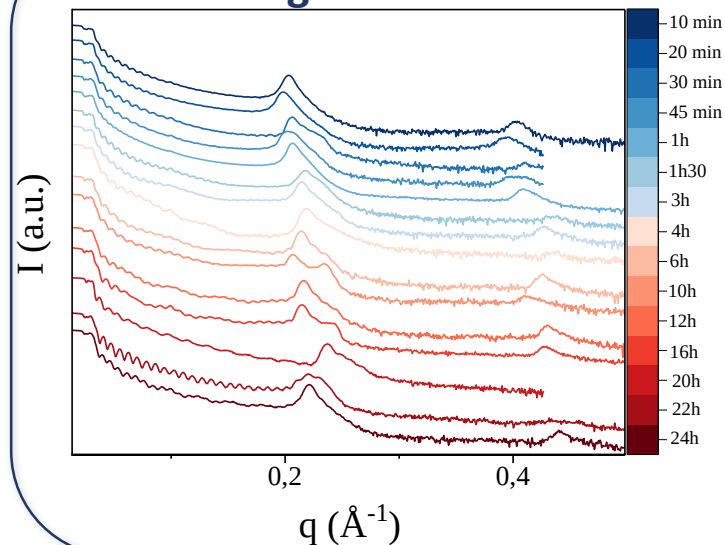
^{36}Ar - $dE/dx = 4,5 \text{ keV/nm} + 600^\circ\text{C}/4\text{h}$



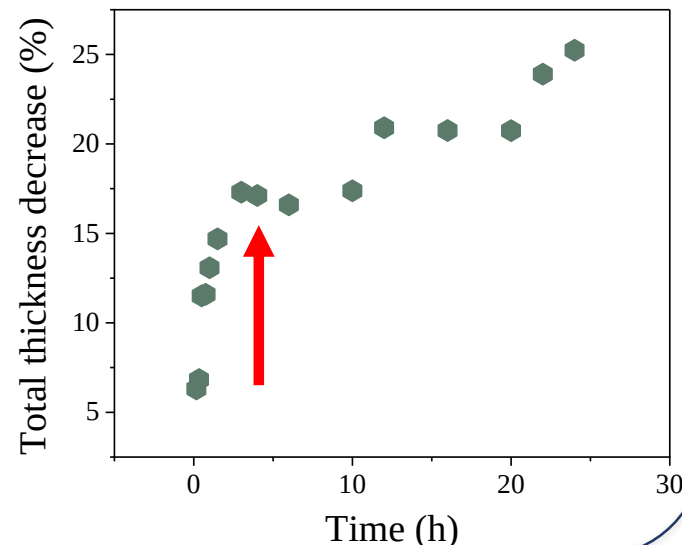
Densification



Heating 600°C



Densification

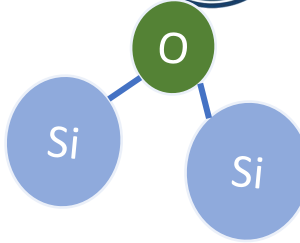


- Decrease in overall intensity $\rightarrow$ Interfacial roughness increase
- Irradiation in electronic regime $\rightarrow$ Additional effect temperature + irradiation

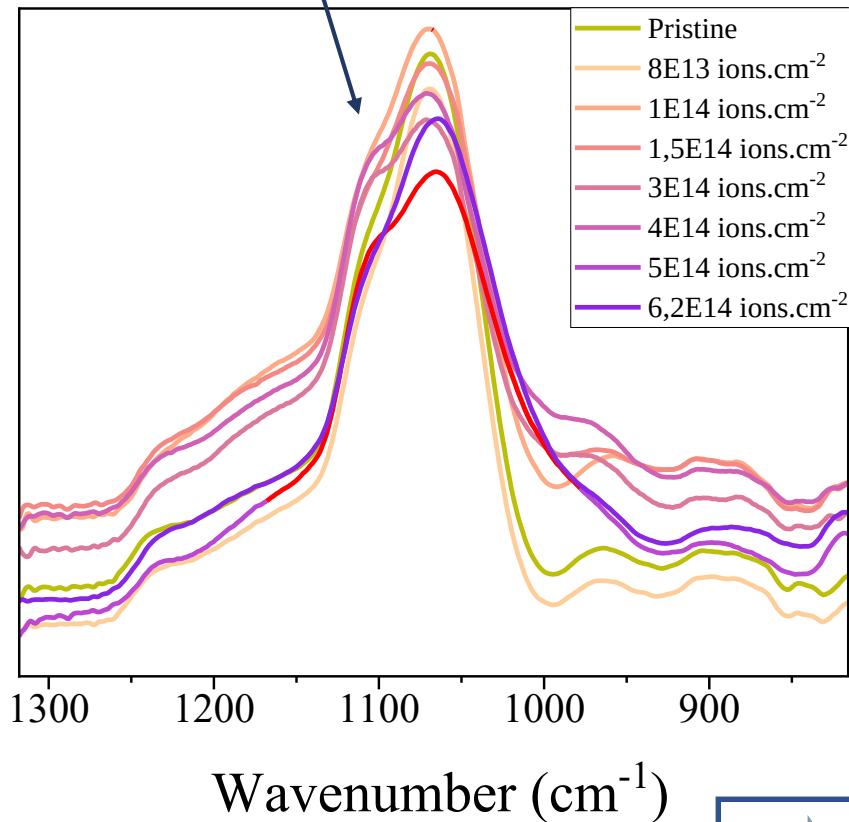
Mesoporous silica ICc - FTIR analyses transmission mode



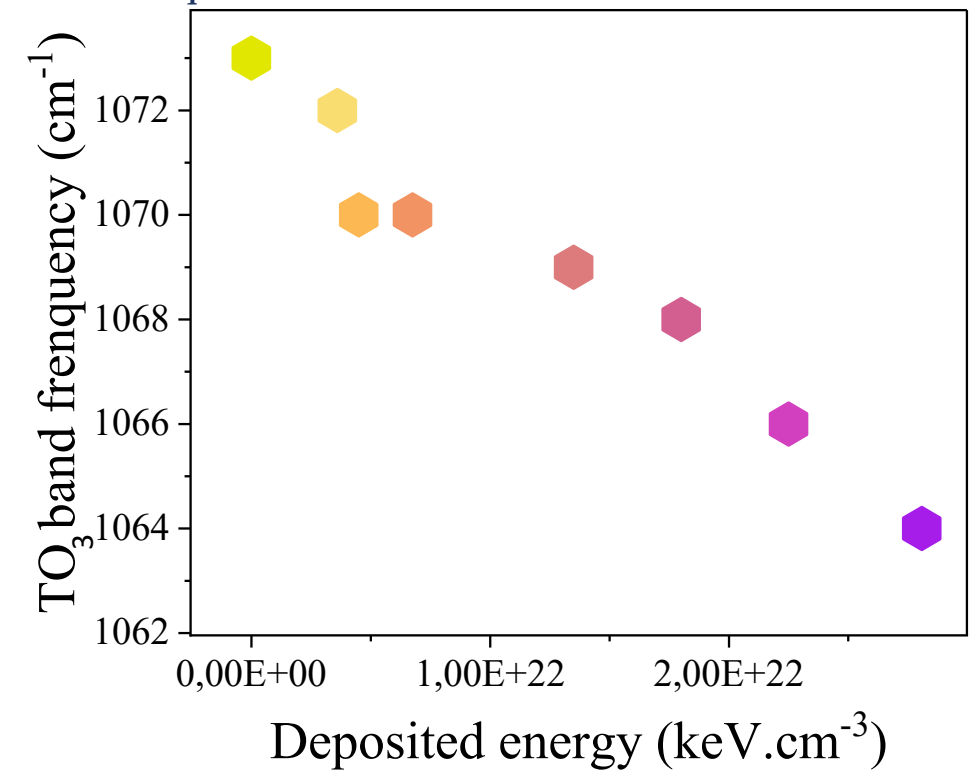
^{36}Ar 0.98 MeV/A



Si-O-Si TO_3 band → Shift and intensity decreases with fluence



The main band shifts to lower frequencies

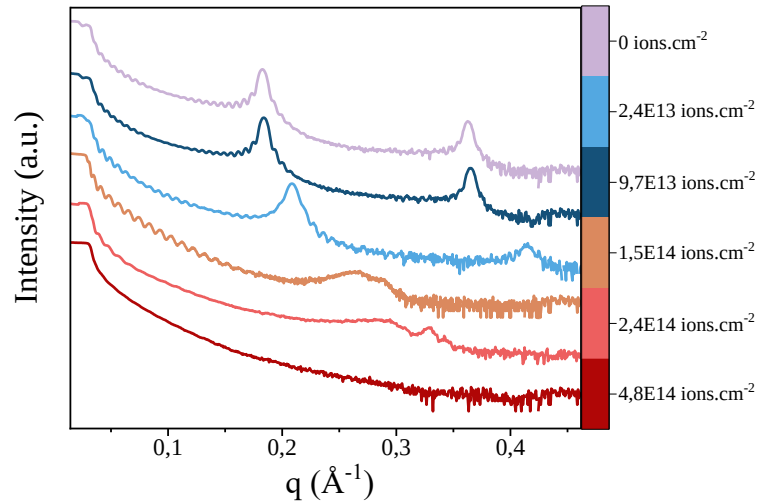


Si-OH intensity decrease → **Si-O-Si condensation**
 TO_3 shift → **Angle decrease**

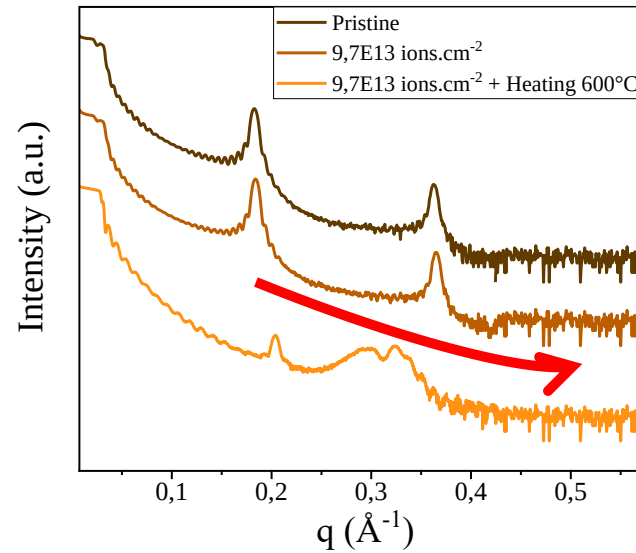
Mesoporous silica ICc - combined effect of T + radiation



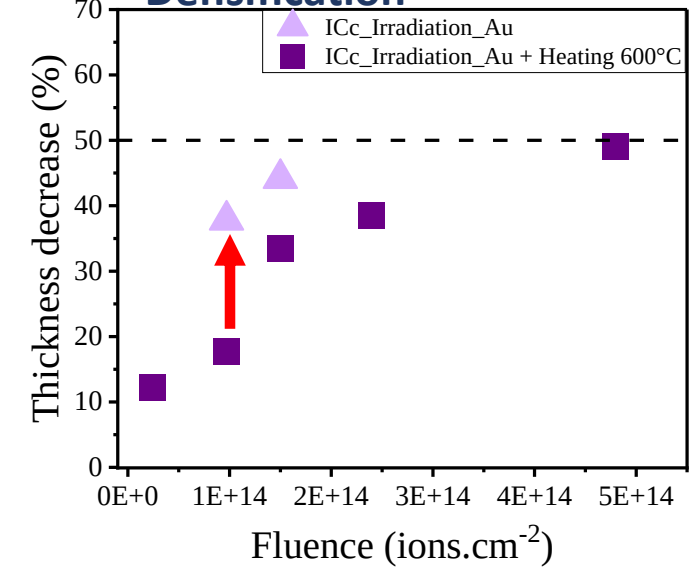
^{197}Au 0,5MeV-dE/dx=4,2 keV/nm



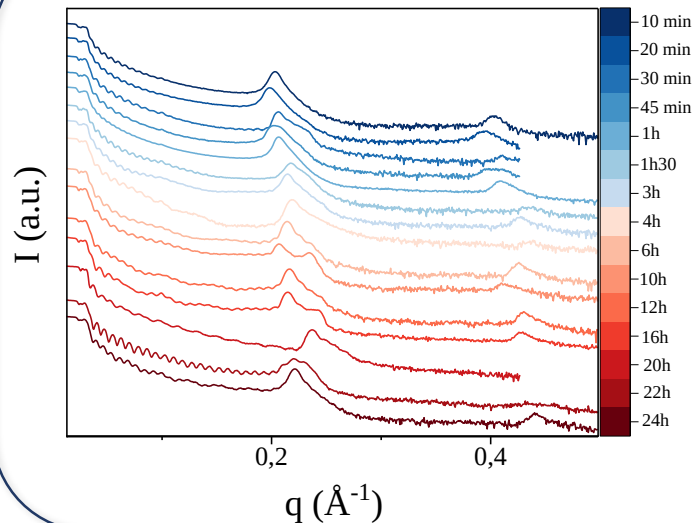
^{197}Au -dE/dx=4,2keV/nm+600°C/20min



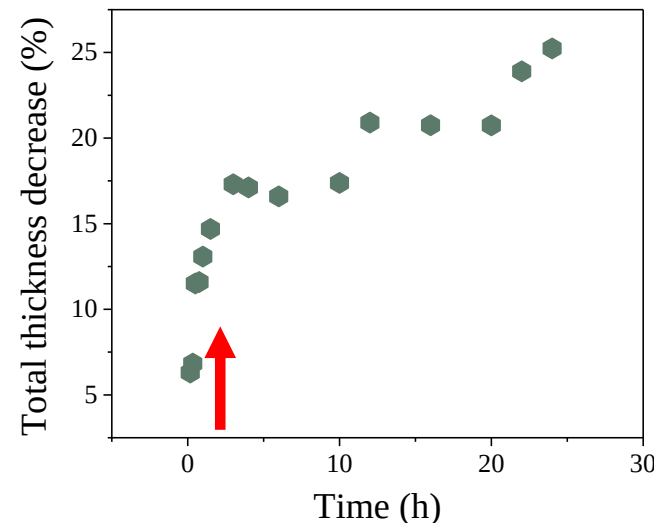
Densification



Heating 600°C



Densification



Irradiation ballistic regime



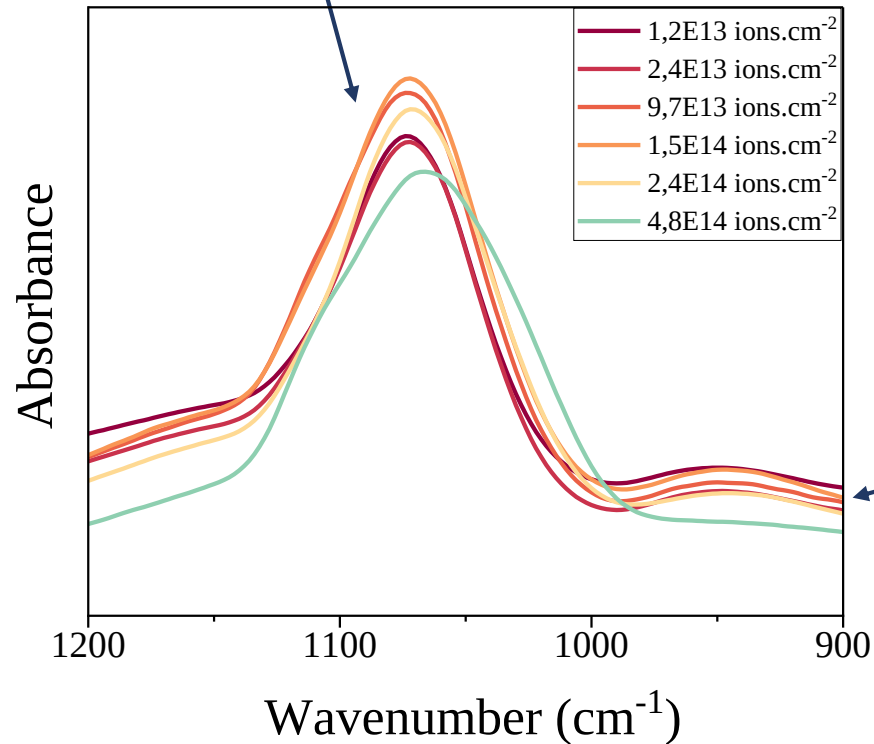
Additional effect
temperature + irradiation

Mesoporous silica ICc - FTIR analyses transmission mode

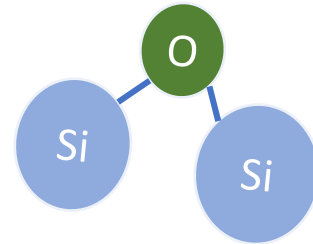
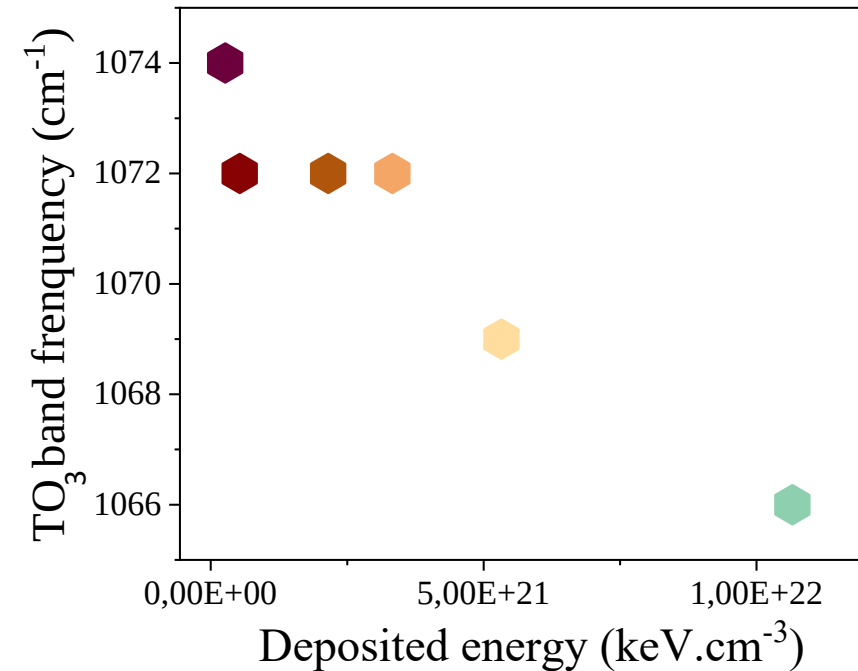


^{197}Au 0.5 MeV

Si-O-Si TO_3 band → Shift and intensity decreases with fluence

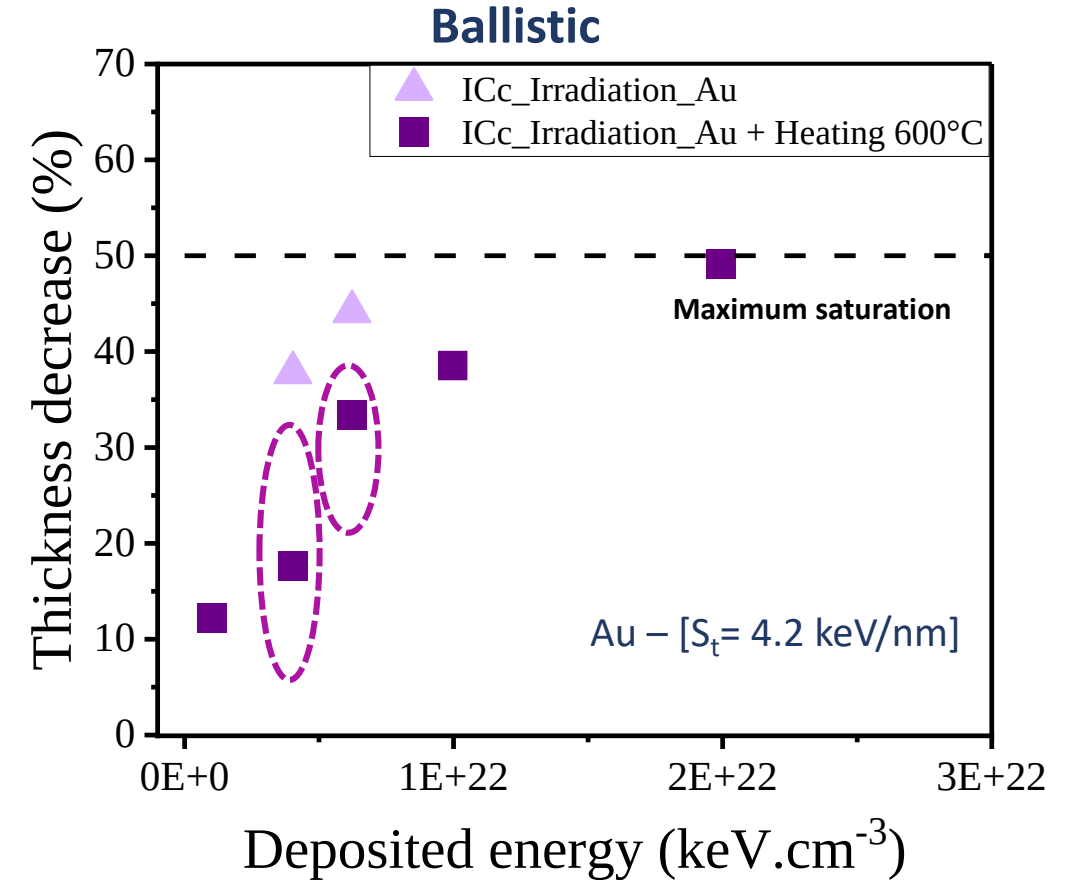
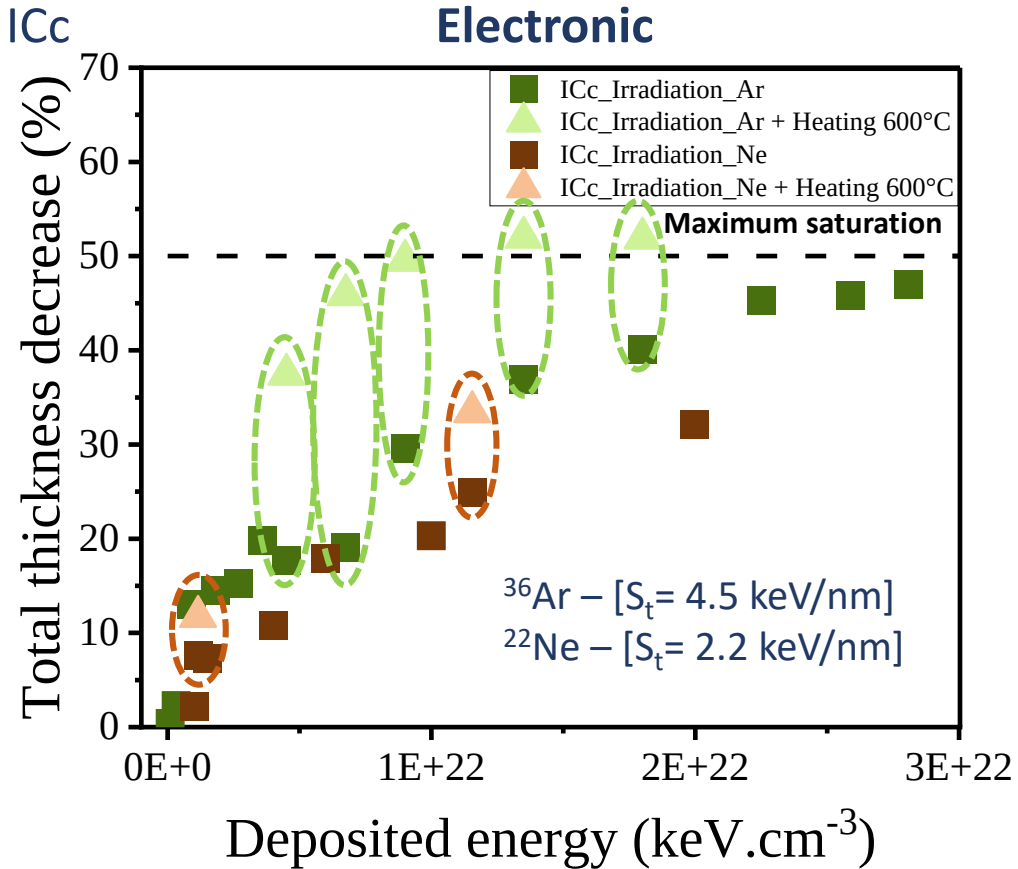


TO_3 band shifts to lower frequencies



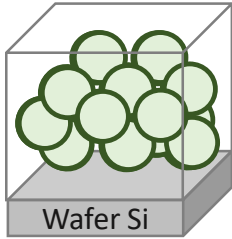
Si-OH intensity decrease → **Si-O-Si condensation**
 TO_3 shift → **Angle decrease**

Results irradiation vs heating : ballistic/electronic effects



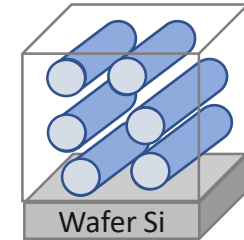
- Same trend in densification processes
 - ✓ Similar deposited energy to reach saturation
 - ✓ Similar densification shift due to heating effect

Irradiation ICc VS IPc



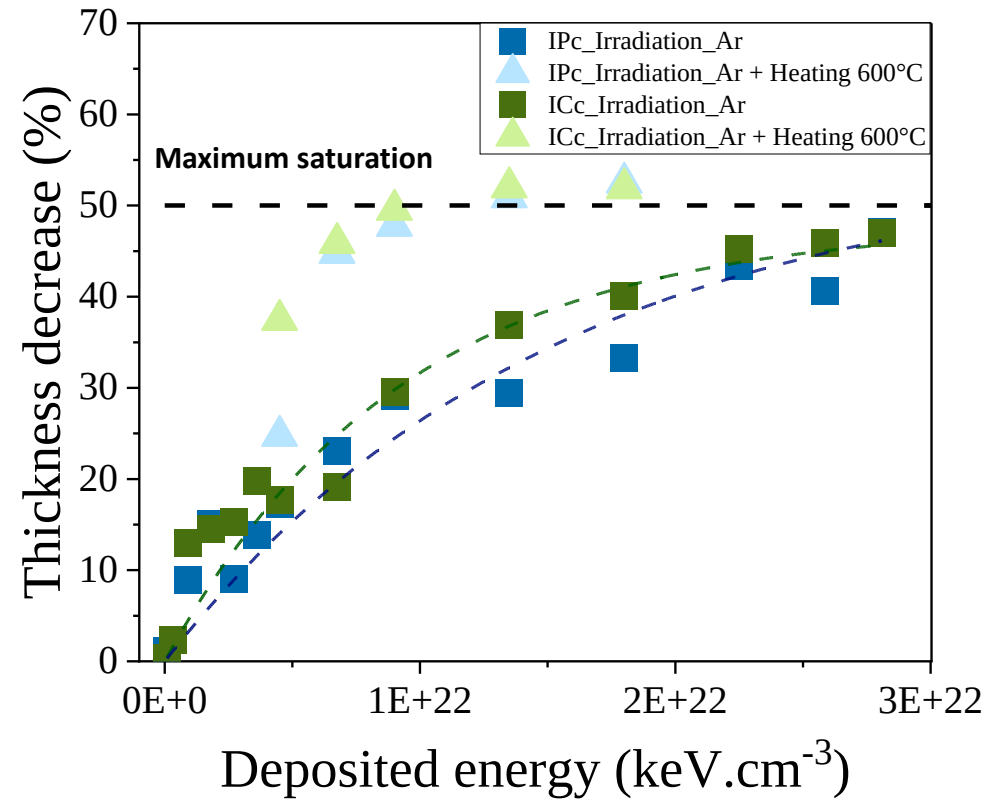
ICc

3D Spherical pore
diameter 2-3 nm



IPc

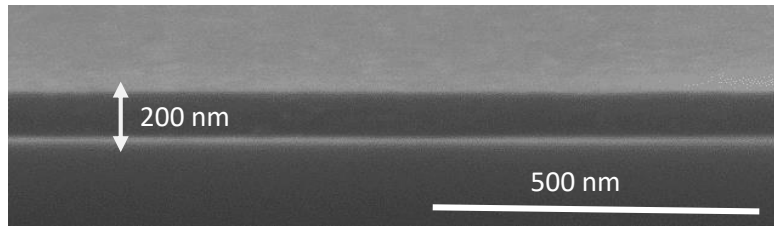
2D Cylindrical pore
diameter 4 nm



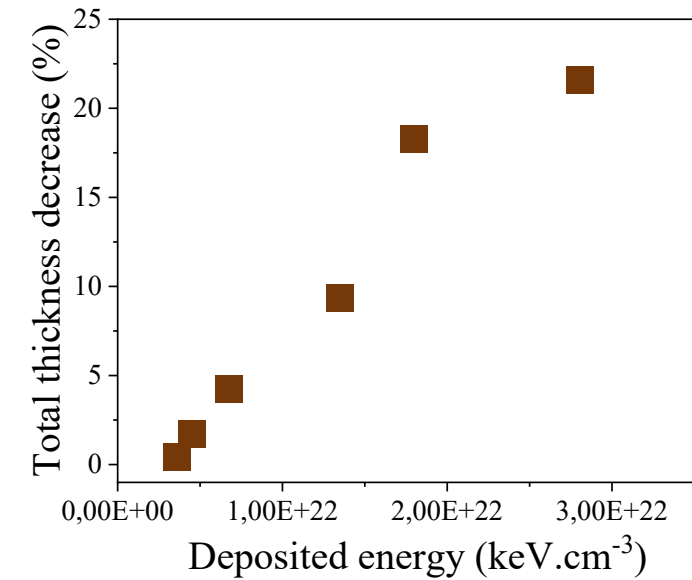
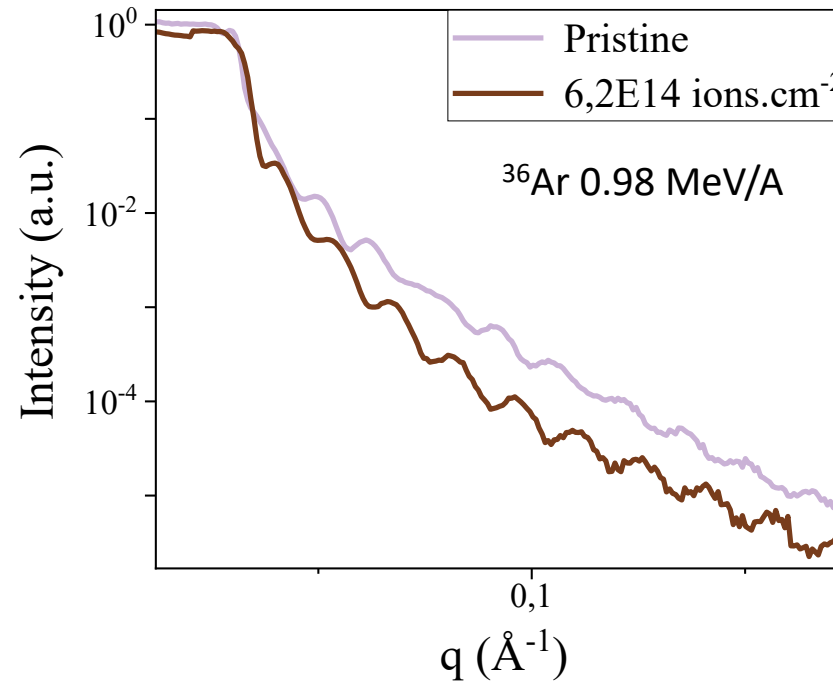
No change with the structure

Preliminary results on mesoporous carbon

- First step : mesoporous carbon powder
 - Study of specific surface area = 560 m²/g
- Second step : adaptation of the protocol to thin films



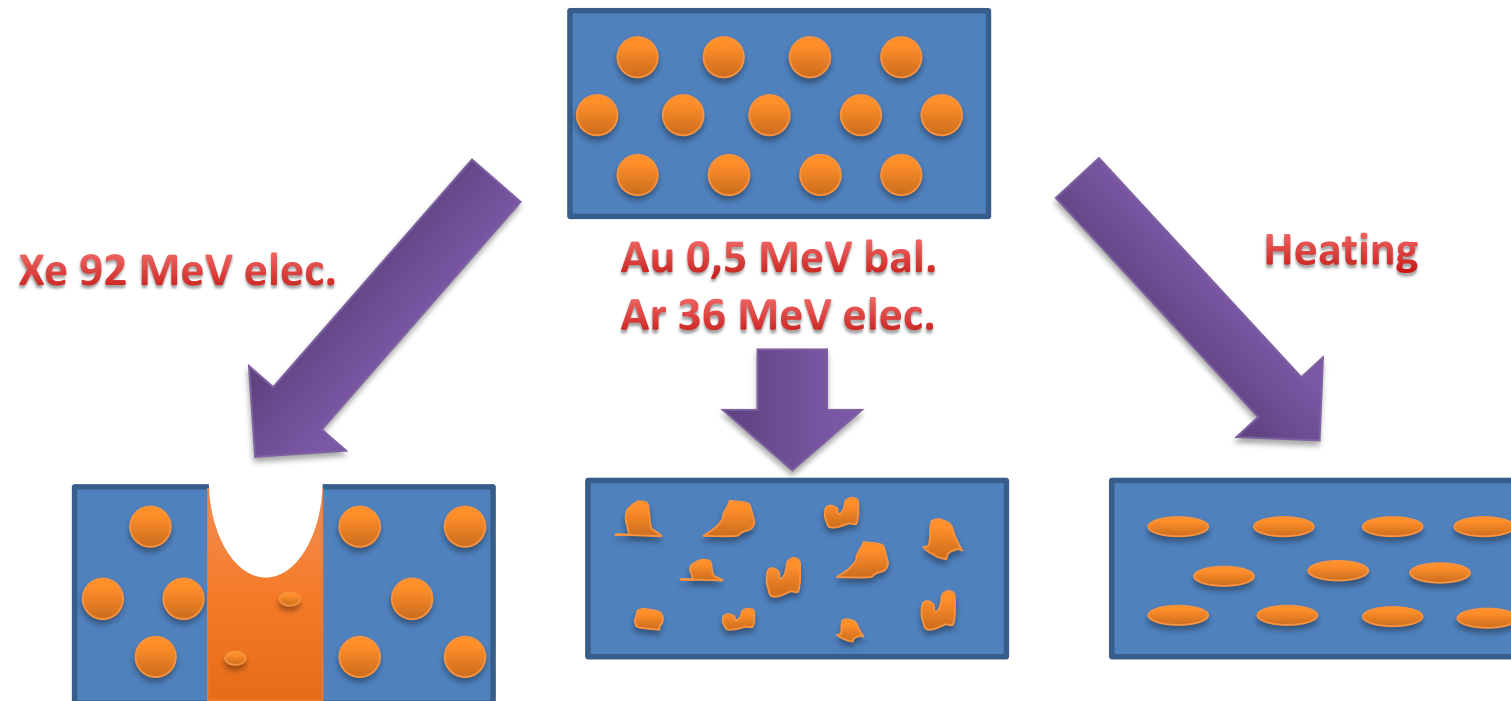
Cross-section SEM



Mesoporous silica

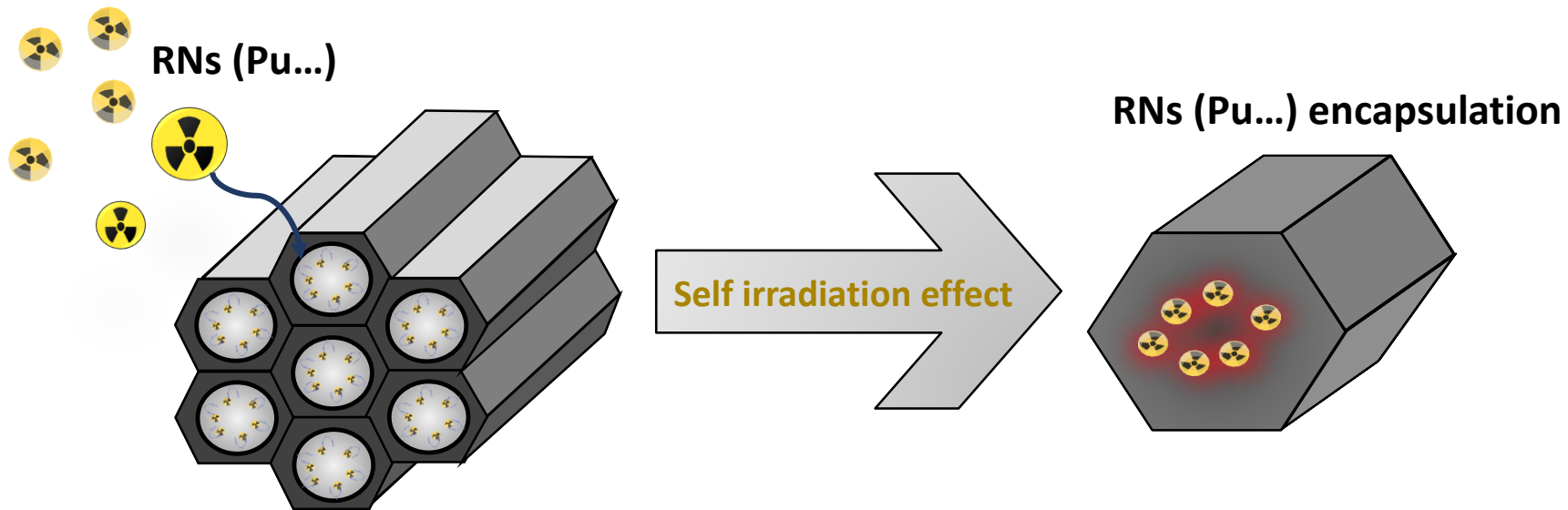
- Ion irradiation makes **collapse** and **densification** of mesoporous silica
- Irradiation + heating → **cumulative processes**
- Same behavior with regard to densification during irradiation in ballistic and electronic regimes → **Possible mechanism** : "low temperature sintering" in relation with diffusion under irradiation

Illustration showing pore collapse due to stress (Irradiation/Heating)



Application :

- Decontamination of radioactive effluents by a two-in-one process “Separation/Conditioning”
- ANR project **AUTOMACT** <https://anr.fr/Project-ANR-18-CE05-0016>
“Solid fixation and AUTO-conditioning of ACTinide elements coming from contaminated liquid outflows”





Acknowledgments

ICSM : V. Proust, S. Dourdain, B. Siboulet

DPME Marcoule : J.M Delaye

PhD students J. Lin, Y. Lou, P. de Laharpe

JRC : O. Walter



Thanks for listening !

Any question ?

